

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Arup Bhattacharyya

Title: HIGH-PERFORMANCE ONE-TRANSISTOR MEMORY CELL

Docket No.: 1303.111US1

Filed: July 2, 2003

Examiner: Fazli Erdem

Serial No.: 10/612,793

Due Date: N/A

Group Art Unit: 2826

**MS Amendment**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

- ☒ Supplemental Information Disclosure Statement (2 pgs.), Form 1449 (1 pg.).
- ☒ Authorization to charge Deposit Account 19-0743 in the amount of \$180.00 to cover the fee for consideration of Information Disclosure Statement under 97(c).

**If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.**

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

Customer Number 21186

By: 

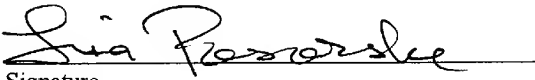
Atty: Marvin L. Beekman

Reg. No. 38,377

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being filed using the USPTO's electronic filing system EFS-Web, and is addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 29 day of January, 2007.



Name

  
Signature

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

(GENERAL)